

## BAT54/A/C/S SCHOTTKY BARRIER DIODE

## **FEATURES**

Extremely Fast Switching Speed











## MAXIMUM RATINGS (T<sub>a</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>			
Working Peak Reverse Voltage	$V_{RWM}$	30	V	
DC Blocking Voltage	$V_R$			
Forward Continuous Current	I <sub>FM</sub>	200	mA	
Non-repetitive Peak Forward Surge Current @ t=8.3ms	I <sub>FSM</sub>	600	mA	
Repetitive Peak Forward Current @ $t \le 1$ s, $\delta \le 0.5$	I <sub>FRM</sub>	300	mA	
Power Dissipation	P <sub>D</sub>	200	mW	
Thermal Resistance from Junction to Ambient	R <sub>OJA</sub>	500	°C/W	
Operating Junction Temperature Range	Tj	-40 ~ +125	$^{\circ}$	
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150	°C	

## **ELECTRICAL CHARACTERISTICS(Ta=25℃ unless otherwise specified)**

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions
Reverse voltage	V <sub>(BR)</sub>	30			V	I <sub>R</sub> =100μA
Forward voltage	V <sub>F</sub>			0.24	V	I <sub>F1</sub> =0.1mA
				0.32	V	I <sub>F2</sub> =1mA
				0.40	V	I <sub>F3</sub> =10mA
				0.50	V	I <sub>F4</sub> =30mA
				1	V	I <sub>F5</sub> =100mA
Reverse current	I <sub>R</sub>			2	μA	V <sub>R</sub> =25V
Diode capacitance	C <sub>D</sub>			10	pF	V <sub>R</sub> =1V,f=1MHz
Reverse recovery time	t <sub>rr</sub>			5	ns	I=IR=10mA
						Irr=0.1×I <sub>R</sub> ,R <sub>L</sub> =100 Ω









